

2MBI400VD-120-50

IGBT Modules

IGBT MODULE (V series) 1200V / 400A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



Maximum Ratings and Characteristics

Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
	Collector-Emitter voltage	Vces			1200	V	
Inverter	Gate-Emitter voltage	V _{GES}			±20	V	
	Collector current	Ic	Continuous	Tc=100°C	400		
				Tc=25°C	520		
		Ic pulse	1ms		800		
		-lc			400		
		-lc pulse	1ms		800		
	Collector power dissipation	Pc	1 device		3330	W	
Junction temperature		Tj			175		
Op	erating junction temperature (under switching conditions)	T _{jop}			150	°C	
Ca	se temperature	Tc			125		
St	orage temperature	Tstg			-40 ~ +125		
Isc	plation voltage between terminal and copper base (*1)	Viso	AC : 1min.		2500	VAC	
9.	rew torque Mounting (*2)				6.0	N m	
30	Terminals (*3)	-			5.0	IN III	

Note *1: All terminals should be connected together during the test. Note *2: Recommendable Value : 3.0-6.0 Nm (M5 or M6) Note *3: Recommendable Value : 2.5-5.0 Nm (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

ems	Cumbala	Complete Conditions			Characteristics		
ems	Symbols	Conditions		min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	2.0	mA
Gate-Emitter leakage current	Iges	$V_{CE} = 0V$, $V_{GE} = \pm 20V$		-	-	400	nA
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 400mA		6.0	6.5	7.0	V
Collector-Emitter saturation voltage	V	V _{GE} = 15V I _C = 400A	Tj=25°C	-	1.95	2.40	V
	V _{CE} (sat)		Tj=125°C	-	2.25	-	
	(terminal)		Tj=150°C	-	2.30	-	
	V _{CE} (sat)		Tj=25°C	-	1.75	2.15	
			Tj=125°C	-	2.05	-	
	(chip)		Tj=150°C	-	2.10	-	
Internal gate resistance	R _{g(int)}	-		-	1.9	-	Ω
Input capacitance Turn-on time	Cies	V_{CE} = 10V, V_{GE} = 0V, f = 1MHz		-	36.4	-	nF
Turn-on time	ton	V_{CC} = 600V, I_{C} = 400A V_{GE} = ±15V, R_{G} = 1 Ω Tj = 150°C, Ls =30nH		-	0.60	-	µsec
	tr			-	0.20	-	
	tr (i)			-	0.05	-	
Turn-off time $\frac{t}{t}$	toff			-	0.80	-	
	tf			-	0.08	-	
Forward on voltage $\frac{V_{\text{F}}}{\text{(tell}}$	V	V _{GE} = 0V I _F = 400A	Tj=25°C	-	1.85	2.30	V
	(terminal)		Tj=125°C	-	2.00	-	
	(terrillial)		Tj=150°C	-	1.95	-	
	V		Tj=25°C	-	1.70	2.15	
	1		Tj=125°C	-	1.85	-	
	(criip)		Tj=150°C	-	1.80	-	
Reverse recovery time	trr	I _F = 400A		-	0.15	-	μsec

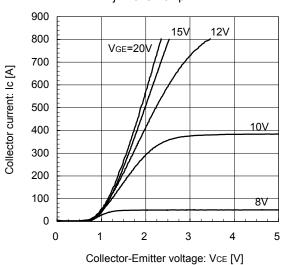
Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items		Conditions	min.	typ.	max.	Units
Thermal resistance (1device)	Rth(I_C)	IGBT	-	-	0.045	°C/W
Thermal resistance (Tuevice)		FWD	-	-	0.077	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.0125	-	

Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

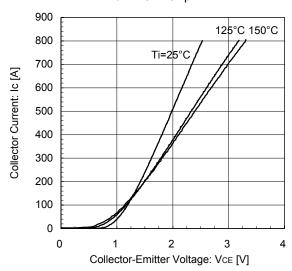
■ Characteristics (Representative)

Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip

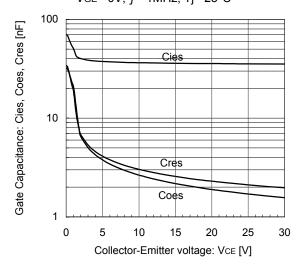


Collector current vs. Collector-Emitter voltage (typ.)

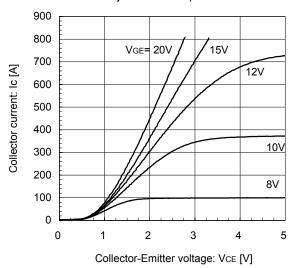
VGE= 15V / chip



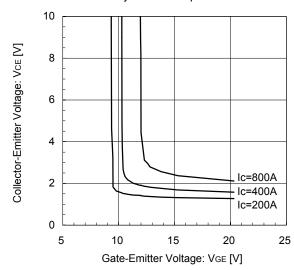
Gate Capacitance vs. Collector-Emitter Voltage VGE= 0V, f= 1MHz, Tj= 25°C



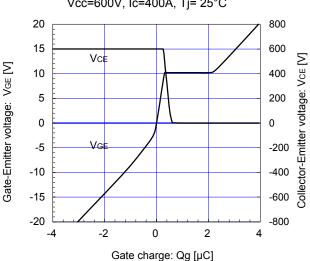
Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip

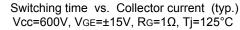


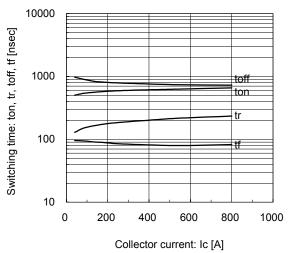
Collector-Emitter voltage vs. Gate-Emitter voltage Tj= 25°C / chip



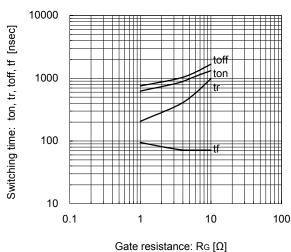
Dynamic Gate Charge (typ.) Vcc=600V, Ic=400A, Tj= 25°C



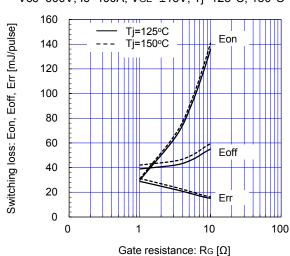




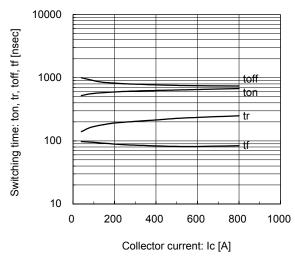
Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=400A, VGE=±15V, Tj=125°C



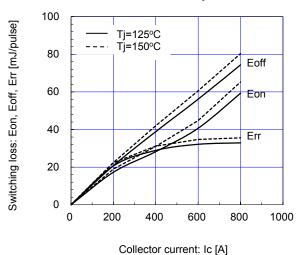
Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=400A, VgE=±15V, Tj=125°C, 150°C



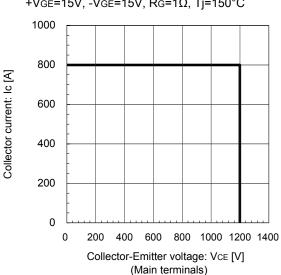
Switching time vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg= 1Ω , Tj=150°C

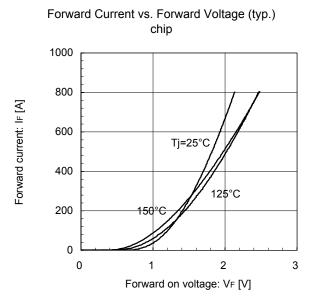


Switching loss vs. Collector current (typ.) Vcc=600V, VgE=±15V, Rg=1Ω, Tj=125°C, 150°C



Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, RG=1 Ω , Tj=150°C

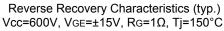


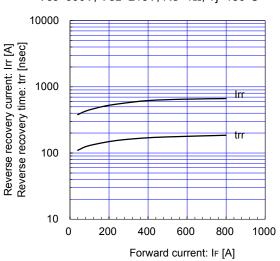


Reverse Recovery Characteristics (typ.) Vcc=600V, VgE=±15V, Rg=1Ω, Tj=125°C

10000

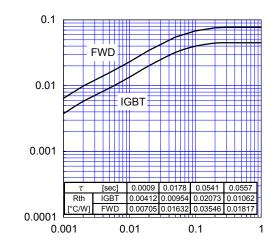
| Vec=200 | VgE=±15V, Rg=1Ω, Tj=125°C |
| Vec=200 | VgE=±15V, Rg=125°C |
| Vec=200 | VgE=±15V, Rg=±15V, Rg=±15V,

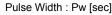


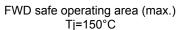


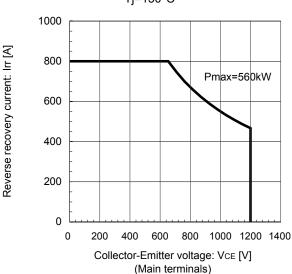
Transient Thermal Resistance (max.)

Forward current: IF [A]





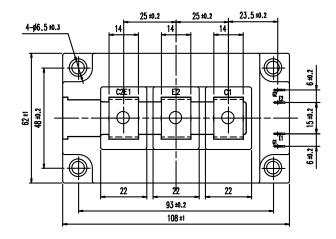


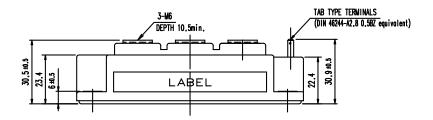


Thermal resistanse: Rth(j-c) [°C/W]

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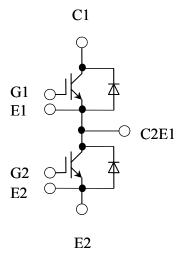
■ Outline Drawings (Unit: mm)





Weight: 370g (typ.)

■ Equivalent Circuit



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- · Machine tools
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IGBT Modules

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